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TEST REPORT

of

FCC CFR 47 part 1, 1.1307(b), 1.1310

FCC ID: A3LEPP3100

Equipment Under Test : WIRELESS CHARGER

Model Name : EP-P3100

Applicant : Samsung Electronics Co., Ltd.

Manufacturer : Samsung Electronics Co., Ltd.

Date of Receipt : 2018.06.04

Date of Test(s) : 2018.06.11 ~ 2018.06.29

Date of Issue : 2018.06.29

In the configuration tested, the EUT complied with the standards specified above.

Tested By: Date: 2018.06.29 **Nancy Park Technical** Date: 2018.06.29 Manager: Jungmin Yang



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1. General information

1.1. Testing laboratory

SGS Korea Co., Ltd. (Gunpo Laboratory)

- -Wireless Div. 2FL, 10-2, LS-ro 182beon-qil, Gunpo-si, Gyeongqi-do, Korea, 15807
- -Designation number: KR0150

All SGS services are rendered in accordance with the applicable SGS conditions of service available on request and accessible at http://www.sgs.com/en/Terms-and-Conditions.aspx.

Phone No. : +82 31 688 0901 Fax No. : +82 31 688 0921

1.2. Details of applicant

Applicant Samsung Electronics Co., Ltd.

Address 19 Chapin Rd., Building D, Pine Brook, New Jersey, United States, 07058

Contact Person : Youn, Chan-Ho Phone No. : +1 973 808 6362

1.3. Details of manufacturer

: Samsung Electronics Co., Ltd. Company

Address : Yen Phong 1 Industrial park, Yen Phong District Ninh Province VIETNAM

1.4. Description of EUT

Kind of Product	WIRELESS CHARGER				
Model Name	EP-P3100				
Power Supply	DC 5.0 V, DC 9.0 V				
	DC 5 V Wireless Charger DC 9 V Wireless Charg				
Frequency Range	Ant. 1: 110 kHz ~ 148 kHz Ant. 2: 110 kHz ~ 148 kHz	Ant. 1: 125 kHz ~ 148 kHz			
Antenna Type	Inductive loop coil antenna				
H/W Version	EP-P3100_0.2				
S/W Version	-				

1.5. Declaration by the manufacturer

- The EUT has 2 inductive loop coil antennas and can be operating individually for mobile and gear. (For the details, please refer to Test setup photo)



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1.6. Test Equipment List

Equipment	Manufacturer	Model	S/N	Cal. Date	Cal. Interval	Cal. Due
E-Field Probe	D.A.R.E!! Instruments	RadiSense 4	13I00444SNO04	Jun. 21, 2018	Annual	Jun. 21, 2019
Magnetic Field Sensor	HIOKI	1087-C1	3472	Dec. 26, 2017	Annual	Dec. 26, 2018
Magnetic Field Hitester	HIOKI	FT3470-50	120429926	May 24, 2018	Annual	May 24, 2019
Anechoic Chamber	SY Corporation	L×W×H (9.6 m×6.4 m×6.6 m)	N/A	N.C.R.	N/A	N.C.R.

▶ Support equipment

Description	Manufacturer	Model	FCC ID
Samsung Mobile Phone	Samsung Electronics Co., Ltd.	SM-G960U	A3LSMG960U
Smart Wearable Device	Samsung Electronics Co., Ltd.	SM-R775U	A3LSMR775U

1.7. Worst case of test configurations

In order to check all kinds of possible configurations, EUT was evaluated with appropriate client and under each charging condition as below table.

Charging mode with client device	Mode		Description
Model: SM-G960U IC Certification: 649E-SMG960U	Operating DC 5 V	Operating DC 9 V	1 % of battery 50 % of battery
Model: SM-R775U IC Certification: 649E-SMR775U	(Ant. 1) (Ant. 2)	(Ant. 1)	99 % of battery

Note:

EUT was investigated with client device under normal charging condition as above then worst value was only reported.

1.7. Test report revision

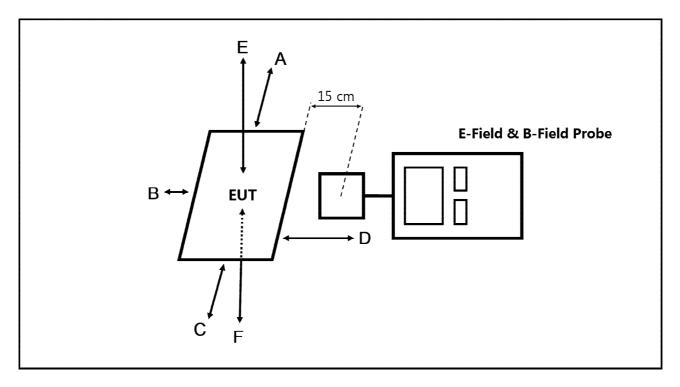
Revision	Report number	Date of Issue	Description		
0	F690501/RF-RTL012820	2018.06.29	Initial		



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2. Test Result

2.1. Test Setup



2.2. Measurement procedure

- a) The RF exposure test was performed in anechoic chamber.
- b) The measurement probe was placed at test distance (15 cm) which is between the edge of the charger and the geometric center of probe.
- c) The highest emission level was recorded and compared with limit as soon as measurement of each points (A, B, C, D, E, F) were completed.
- d) The EUT was measured according to the dictates of KDB 680106 D01 v03.



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2.3. Equipment Approval Considerations item 5 b) of KDB 680106 D01 v03.

- (1) Power transfer frequency is less that 1 Mb.
 - The device operates at a frequency range 110 kHz to 148 kHz.
- (2) Output power from each primary coil is less than or equal to 15 watts.
 - Output power from primary coil: 15 watts.
- (3) The transfer system includes only single primary and secondary coils. This includes charging systems that may have multiple primary coils and clients that are able to detect and allow coupling only between individual pairs of coils.
 - The transfer system including a charging system with multiple primary coils are to detect and allow only between individual pairs of coils.
- (4) Client device is placed directly in contact with the transmitter.
 - Client device is placed directly in contact with the transmitter.
- (5) Mobile exposure conditions only (portable exposure conditions are not covered by this exclusion).
 - Mobile exposure conditions only.
- (6) The aggregate H-field strengths at 15 cm surrounding the device and 20 cm above the top surface from all simultaneous transmitting coils are demonstrated to be less than 50 % of the MPE limit.
 - Refer to following test results. The EUT H-Field Strength levels at 15 cm < 50 % of the MPE H-Field Strength limit 1.63 A/m 0.134 A/m (Max. at 15 cm) < 0.815 A/m



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2.4. Environmental evaluation and exposure limit according to FCC CFR 47 part 1, 1.1307(b), 1.1310

§1.1310: The criteria listed in the following table shall be used to evaluate the environment impact of human exposure to radio frequency (RF) radiation as specified in §1.1307(b), except in the case of portable devices which shall be evaluated according to the provisions of FCC part 2.1093 of this chapter.

TABLE 1 - LIMITS FOR MAXIMUM PERMISSIBLE EXPOSURE (MPE)

Frequency Range (썐)	Electric Field Strength (V/m)	Magnetic Field Strength (A/m)	Power Density (ﷺ/ﷺ)	Average Time (minutes)						
(A) Limits for Occupational /Control Exposures										
0.3-3.0	614	1.63	*(100)	6						
3.0-30	1842/f	4.89/f	*(900/f ²)	6						
30-300	61.4	0.163	1.0	6						
300-1 500			f/300	6						
1 500-100 000			5	6						
	(B) Limits for Ger	neral Population / Unc	ontrol Exposures							
<u>0.3-1.34</u>	<u>614</u>	<u>1.63</u>	*(100)	30						
1.34-30	824/f	2.19/f	*(180/f ²)	30						
30-300	27.5	0.073	0.2	30						
300-1 500			f/1 500	30						
1 500-100 000			1.0	30						

f = frequency in Mbz

^{* =} Plane wave equivalent power density



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2.5. E and H field strength

Ambient temperature : (23 ± 1) °C Relative humidity : 47 % R.H.

2.5.1. E-Field Strength at from the edges surrounding the EUT

Test Condition: DC 5 V Operating mode with client device (1 % battery status of client device)

Frequency Range (妣)	Antenna	Probe Position A (V/m)	Probe Position B (V/m)	Probe Position C (V/m)	Probe Position D (V/m)	Probe Position E (V/m)	Probe Position F (V/m)	Limits (V/m)
440 440	1	6.56	8.58	6.74	5.94	9.23	7.52	C4.4
110 ~ 148	2	3.77	5.23	4.52	5.48	9.84	8.58	614

Test Condition: DC 9 V Operating mode with client device (1 % battery status of client device)

Frequency Range (쌦)	Antenna	Probe Position A (V/m)	Probe Position B (V/m)	Probe Position C (V/m)	Probe Position D (V/m)	Probe Position E (V/m)	Probe Position F (V/m)	Limits (V/m)
125 ~ 148	1	6.71	8.91	7.33	6.32	9.69	8.11	614



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2.5.2. H-Field Strength at from the edges surrounding the EUT

Test Condition: DC 5 V Operating mode with client device (1 % battery status of client device)

Frequency Range (紀)	Antenna	Probe Position A (A/m)	Probe Position B (A/m)	Probe Position C (A/m)	Probe Position D (A/m)	Probe Position E (A/m)	Probe Position F (A/m)	Limits (A/m)
110 149	1	0.082	0.049	0.018	0.119	0.035	0.037	1.63
110 ~ 148	2	0.082	0.049	0.018	0.119	0.035	0.037	1.03

Test Condition: DC 9 V Operating mode with client device (1 % battery status of client device)

Frequency Range (紀)	Antenna	Probe Position A (A/m)	Probe Position B (A/m)	Probe Position C (A/m)	Probe Position D (A/m)	Probe Position E (A/m)	Probe Position F (A/m)	Limits (A/m)
125 ~ 148	1	0.098	0.083	0.036	0.134	0.044	0.042	1.63

Remark:

1. H-field strength (A/m) = B-field (μ T) / 1.25

- End of the Test Report -